

2SJ76, 2SJ77, 2SJ78, 2SJ79

Silicon P Channel MOS FET

REJ03G0122-0200

(Previous: ADE-208-1179)

Rev.2.00 Sep 07, 2005

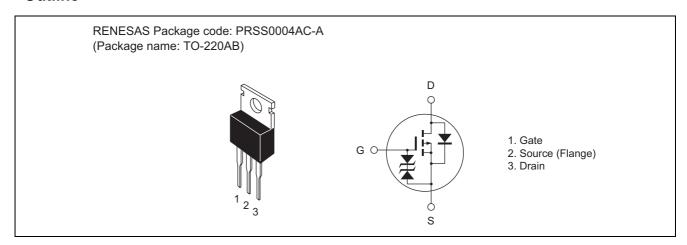
Description

High frequency and low frequency power amplifier, high speed power switching Complementary pair with 2SK213, 2SK214, 2SK215, 2SK216

Features

- Suitable for direct mounting
- High forward transfer admittance
- Excellent frequency response
- Enhancement-mode

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Value	Unit
Drain to source voltage	2SJ76	V _{DSX}	-140	V
	2SJ77		-160	
	2SJ78		-180	
	2SJ79		-200	
Gate to source voltage		V _{GSS}	±15	V
Drain current		I _D	-500	mA
Body to drain diode reverse drain current		I _{DR}	-500	mA
Channel dissipation		Pch	1.75	W
		Pch Note 1	30	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-45 to +150	°C

Note: 1. Value at Tc = 25°C

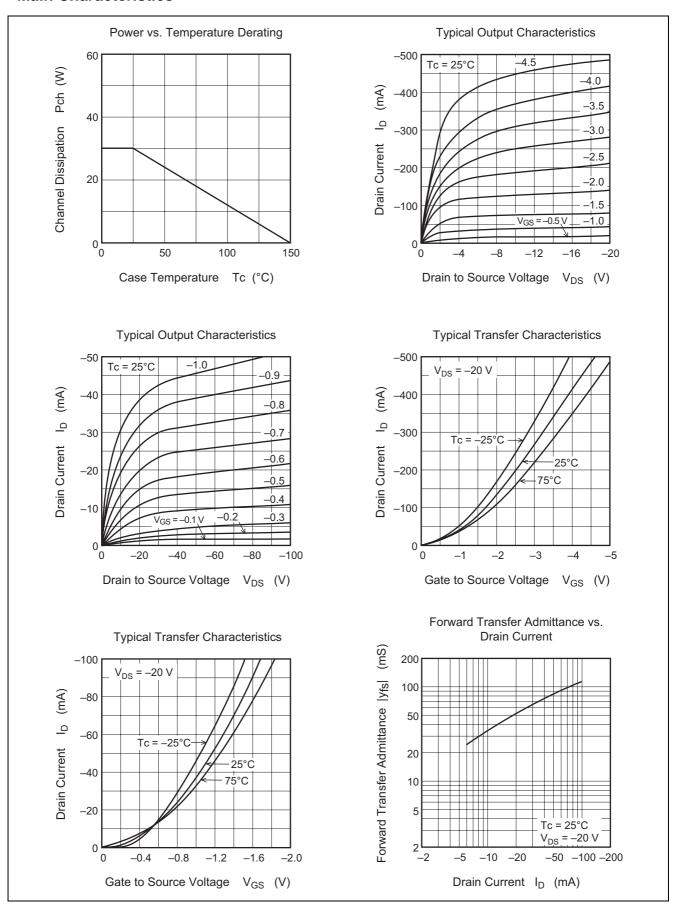
Electrical Characteristics

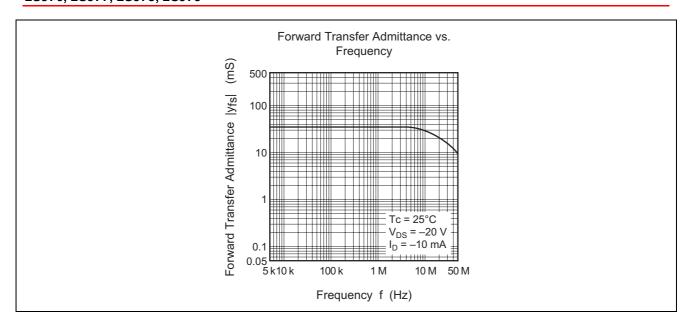
 $(Ta = 25^{\circ}C)$

Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown	2SJ76	V _{(BR) DSX}	-140	_	_	V	$V_{GS} = 2 \text{ V}, I_D = -1 \text{ mA}$
voltage	2SJ77		-160	_	_	V	
	2SJ78		-180	_	_	V	
	2SJ79		-200	_	_	V	
Gate to source breakdown voltage		V _{(BR) GSS}	±15	_	_	V	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0$
Gate to source cutoff voltage		V _{GS (on)}	-0.2	_	-1.5	V	$I_D = -10 \text{ mA}, V_{DS} = -10 \text{ V}^{\text{Note 2}}$
Drain to source saturation voltage		V _{DS (sat)}	_		-2.0	V	$I_D = -10 \text{ mA}, V_{GS} = 0^{\text{Note 2}}$
Forward transfer admittance		y _{fs}	20	35	_	mS	$I_D = -10 \text{ mA}, V_{DS} = -20 \text{ V}^{\text{Note 2}}$
Input capacitance		Ciss	_	120	_	pF	$V_{DS} = -10 \text{ V}, I_D = -10 \text{ mA},$
Reverse transfer capacitance		Crss	_	4.8	_	pF	f = 1 MHz

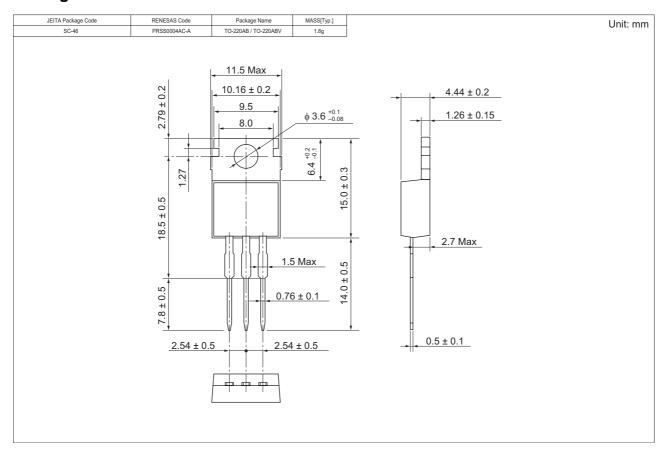
Note: 2. Pulse test

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SJ76-E	500 pcs	Box (Sack)
2SJ77-E	500 pcs	Box (Sack)
2SJ78-E	500 pcs	Box (Sack)
2SJ79-E	500 pcs	Box (Sack)

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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